

DT05 Rec'd PCT/PTO 31 JAN 2005  
Attorney Docket # 5367-146PUS

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re National Phase PCT Application of  
Dominik EISERT et al.  
International Appln. No.: PCT/DE2003/002071  
International Filing Date: June 20, 2003  
For: GaN-Based Radiation-Emitting Thin-Layered  
Semiconductor Component

**PRELIMINARY AMENDMENT**

Mail Stop **PCT**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

S I R:

Prior to examination of the above-identified application please amend the application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 13 of this paper.

**Amendments to the Abstract** are on page 22 of this paper

**Amendments to the Drawings** begin on page 23 of this paper and include an attached replacement sheet.

**Remarks/Arguments** begin on page 24 of this paper.